



PNP GENERAL PURPOSE SWITCHING TRANSISTOR

VOLTAGE 40V POWER 225mW

FEATURES

PNP epitaxial silicon, planar design

Collector-emitter voltage $V_{CE} = -40V$

Collector current I_C =-600mA

Complimentary (NPN) device: MMBT4401

Lead free in compliance with EU RoHS 2011/65/EU directive

Green molding compound as per IEC61249 Std. .

(Halogen Free)

MECHANICAL DATA

Case: SOT-23

Terminals: Solderable per MIL-STD-750, Method 2026

Approx Weight: 0.0003 ounces, 0.0084 grams

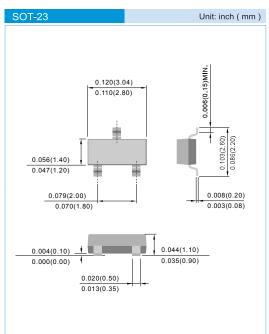
Marking: M3A

Top View

Collector

BASE

Collector



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Collector - Emitter Voltage	V _{CEO}	-40	V
Collector - Base Voltage	V_{CBO}	-40	V
Emitter – Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous	$I_{\rm C}$	-600	mA
Max Power Dissipation (Note 1)	P _{TOT}	225	mW
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^{\circ}\!\mathbb{C}$

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	VALUE	UNIT
Thermal Resistance , Junction to Ambient (Note 1)	$R_{ heta JA}$	556	°C/W

Note 1: Transistor mounted on FR-4 board 70 x 60 x 1mm. using minimum recommended pad.





ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise noted)

PARAMETER	SYMBOL	Test Condition	MIN.	TYP.	MAX.	UNIT
Collector - Emitter Breakdown Voltage	V _(BR) CEO	I _C =-1.0mA, I _B =0	-40	-	-	V
Collector - Base Breakdown Voltage	V _(BR) CBO	I _C =-100uA, I _E =0	-40	-	-	V
Emitter - Base Breakdown Voltage	V _(BR) EBO	I _E =-100uA, I _C =0	-5.0	-	-	V
Base Cutoff Current	$I_{ m BEV}$	V_{CE} =-35V, V_{EB} =-0.4V	-	-	-100	nA
Collector Cutoff Current	I _{CEX}	V_{CE} =-35V, V_{EB} =-0.4V	-	-	-100	nA
DC Current Gain	$h_{ m FE}$	I _C =-0.1mA, V _{CE} =-1.0V	30	-	-	-
		I_C =-1.0mA, V_{CE} =-1.0V	60	-	-	
		I_{C} =-10mA, V_{CE} =-1.0V	100	-	-	
		I _C =-150mA, V _{CE} =-2.0V	100	-	300	
		I _C =-500mA, V _{CE} =-2.0V	20	-	-	
Collector - Emitter Saturation Voltage	V _{CE(SAT)}	I _C =-150mA, I _B =-15 mA	-	-	-0.4	17
		I_{C} =-500mA, I_{B} =-50mA	-	-	-0.75	V
Base - Emitter Saturation Voltage	V _{BE(SAT)}	I _C =-150mA, I _B =-15mA	-0.75	-0.750.95		
		I_{C} =-500mA, I_{B} =-50mA	-	-	-1.3	V
Current-Gain – Bandwidth Product	f_T	I _C =-20mA, V _{CE} =-10V, f=100MHz	200	-	-	MHz
Collector - Base Capacitance	C _{CBO}	V_{CB} =-5.0V, I_{E} =0, f=1MHz	-	-	8.5	pF
Emitter - Base Capacitance	C _{EBO}	V _{CB} =-0.5V, I _C =0, f=1MHz	-	-	30	pF
Delay Time	t _d	V _{CC} =-30V, V _{BE} =-2.0V,	-	-	15	ns
Rise Time	t _r	I _C =-150mA, I _{B1} =-15mA	-	-	20	ns
Storage Time	t _s	V _{CC} =-30V, I _C =-150mA,	-	-	225	ns
Fall Time	t_{f}	$I_{B1} = I_{B2} = 15 \text{mA}$	-	-	30	ns

SWITCHING TIME EQUIVALENT TEST CIRCUITS

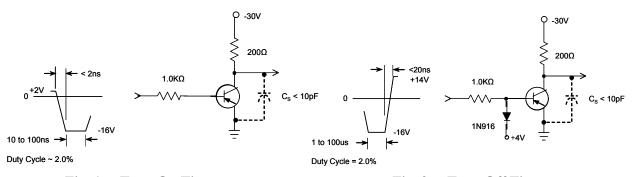


Fig. 1. Turn-On Time

Fig. 2. Turn-Off Time





ELECTRICAL CHARACTERISTICS CURVES

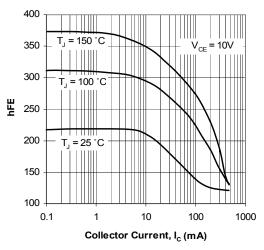


Fig. 3. Typical h_{FE} vs Collector Current

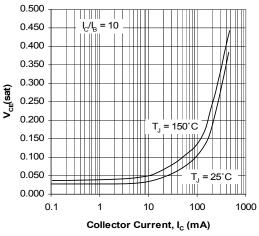


Fig. 5. Typical V_{CE} (sat) vs Collector Current

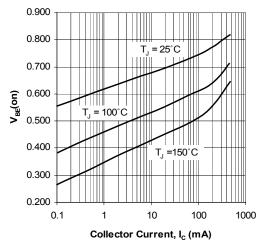


Fig. 4. Typical V_{BE} vs Collector Current

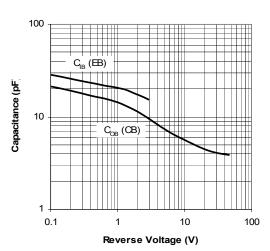
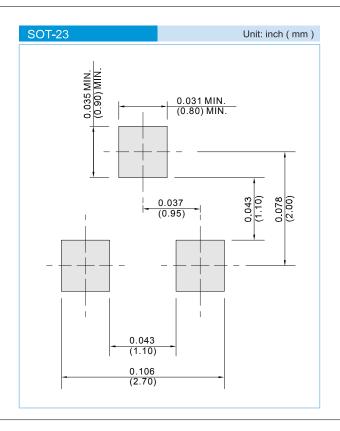


Fig. 6. Typical Capacitances vs Reverse Voltage

MOUNTING PAD LAYOUT



ORDER INFORMATION

Packing information

T/R - 12K per 13" plastic Reel

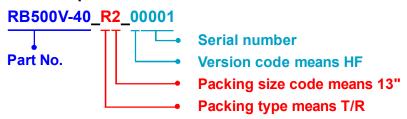
T/R - 3K per 7" plastic Reel



Part No_packing code_Version

MMBT4403_R1_00001 MMBT4403_R2_00001

For example:



Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	Α	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	В	13"	2			
Tube Packing (T/P)	Т	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Υ			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			

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